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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
09/629,407	08/01/2000	Allan Rosencwaig	TWI-10820	6057	
759	05/08/2003				
STALLMAN & POLLOCK LLP			EXAMINER		
Attn: Micheal A			SONG, HOON K		
Suite 290 San Francisco, C	CA 94105		ART UNIT	PAPER NUMBER	
•			2882		

DATE MAILED: 05/08/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

	Applica	tion No.	Applicant(s)	
	09/629,	407	ROSENCWAIG ET AL.	
Office Action Summar	Examine	er	Art Unit	
	Hoon K	_	2882	
The MAILING DATE of this con Period for Reply	nmunication appears on th	he cover sheet with th	ne correspondence address	
A SHORTENED STATUTORY PERIOD THE MAILING DATE OF THIS COMITIVE COM	MUNICATION. visions of 37 CFR 1.136(a). In no e s communication. thirty (30) days, a reply within the st num statutory period will apply and or reply will, by statute, cause the ap onths after the mailing date of this c	event, however, may a reply be atutory minimum of thirty (30) will expire SIX (6) MONTHS to become ABANX	e timely filed  days will be considered timely.  rom the mailing date of this communic	cation.
1) Responsive to communication	(s) filed on 24 February :	2003		
2a) This action is FINAL.	2b)⊠ This action i			
3) Since this application is in con	•		prosecution as to the mer	its is
closed in accordance with the Disposition of Claims	practice under Ex parte (	Quayle, 1935 C.D. 11	l, 453 O.G. 213.	
4)⊠ Claim(s) <u>1-31</u> is/are pending in	the application			
4a) Of the above claim(s)		onsideration		
5) Claim(s) is/are allowed.	13/are withdrawn from Ct	onsideration.		
6)⊠ Claim(s) <u>1-8,10-18,20-27 and 2</u>	9-31 is/are rejected			
7)⊠ Claim(s) <u>9,19 and 28</u> is/are obje				
8) Claim(s) are subject to re		requirement		
Application Papers		4		
9)☐ The specification is objected to b	y the Examiner.			
10) The drawing(s) filed on is	/are: a)□ accepted or b)□	objected to by the E	xaminer.	
Applicant may not request that an	y objection to the drawing(s	b) be held in abeyance.	See 37 CFR 1.85(a).	
11) The proposed drawing correction	ı filed on <u>24 February 20</u> 0	<u>03</u> is: a)⊠ approved	b) disapproved by the E:	xaminer.
If approved, corrected drawings a	• •	Office action.		
12)☐ The oath or declaration is object	·			
Priority under 35 U.S.C. §§ 119 and 120				
13) Acknowledgment is made of a c		nder 35 U.S.C. § 119	9(a)-(d) or (f).	
a) All b) Some * c) None				
1.☐ Certified copies of the prid				
2. Certified copies of the prid			<del></del>	
<ol> <li>Copies of the certified cop application from the Ir</li> <li>* See the attached detailed Office a</li> </ol>	nternational Bureau (PCT	Rule 17.2(a)).	•	
14)☐ Acknowledgment is made of a cla	im for domestic priority u	nder 35 U.S.C. § 119	9(e) (to a provisional applic	cation).
<ul> <li>a) ☐ The translation of the foreign</li> <li>15)☒ Acknowledgment is made of a class</li> </ul>	n language provisional ap	oplication has been re	eceived.	·
Attachment(s)	•			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review 3) Information Disclosure Statement(s) (PTO-144)			ary (PTO-413) Paper No(s) al Patent Application (PTO-152)	<b>-</b> ·
S. Patent and Trademark Office PTO-326 (Rev. 04-01)	Office Action Summa	ıry	Part of Paper N	

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## **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-8, 10-18, 20-27 and 29-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Koppel (US 5619548).

Regarding claims 1, 11, 20 and 29, Koppel teaches a method and apparatus (figure 2) comprising:

Generating a probe (55) beam of X-rays (31);

Directing (37) the probe beam onto the surface of the wafer such that the spot size of the probe beam is large relative to the feature size of the pattern on said surface of said patterned wafer;

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Measuring the intensity of various X-rays as reflected from the wafer to generate reflectivity data (column 5 line 37+); and

Analyzing the reflectivity data to determine characteristics of the thin film layers (abstract).

However Koppel merely teaches that the spot size of the probe beam is large relative to the feature size of the pattern on the surface of the patterned wafer.

Although Koppel fails to teach the patterned wafer and larger probe size beam, the applicant admitted that prior art teaches that the probe size is much bigger than feature size of the pattern (millimeter vs. micro-meter). Thus, one having ordinary skill in the art would notice that Koppel's probe beam would be larger probe size beam than the pattern.

Furthermore measuring patterned wafer, a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. In a claim drawn to a process of making, the intended use must result in a manipulative difference as compared to the prior art. In this case the applicant fails to describe structural limitation or method of measuring <u>pattered</u> wafer. Accordingly, since Koppel teaches identical measuring apparatus of present invention, one having ordinary skill in the art would be motivated to use Koppel's apparatus to measure any kind of substrate because it would measure the properties i.e. thickness, of the measuring substrate (abstract).

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Regarding claims 2, 12 and 21, Koppel teaches that the characteristics include thin film layer thickness (abstract).

Regarding claim 3-6, 13-16 and 22-25, Koppel teaches about detectors (figure 2).

Regarding claims 7, 17 and 26, Koppel teaches the directing step (figure 2).

Regarding claims 8, 18, 27 and 30, Koppel teaches that the analyzing the reflectivity data step includes applying a Fourier transform (well known figure 6, 7).

Regarding claims 10 and 31, Koppel teaches that the reflectivity data includes data measuring reflected x-ray intensity as a function of angle of incidence (figure 4).

## Allowable Subject Matter

Claims 9, 19 and 28 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: None of the prior art teaches or suggests that the analyzing the reflectivity data step includes applying a transform function to the reflectivity data and further wherein the transform function is chosen based on a comparison of the reflectivity data with x-ray reflectivity data corresponding to measurements made on an unpatterned region of a semiconductor wafer (figure 2, column 6 line 48+).

## Response to Arguments

Applicant's arguments with respect to claims 1-31 have been considered but are most in view of the new ground(s) of rejection.

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## Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoon K Song whose telephone number is 703-308-2736. The examiner can normally be reached on 8:30 AM - 5 PM, Monday - Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim can be reached on 703-305-3492. The fax phone numbers for the organization where this application or proceeding is assigned are 703-746-4858 for regular communications and 703-308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

DAVID V. BRUCE PRIMARY EXAMINER

Hoon Song May 1, 2003